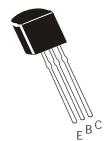


Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



PNP SILICON PLANAR EPITAXIAL TRANSISTOR



MPSA92

TO-92
Plastic Package
For Lead Free Parts, Device
Part # will be Prefixed with
"T"

High Voltage Transistors

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Base Voltage	V_{CBO}	300	V
Collector Emitter Voltage	$V_{\sf CEO}$	300	V
Emitter Base Voltage	V_{EBO}	5.0	V
Collector Current Continuous	I _C	500	mA
Power Dissipation at T _a =25°C	P_D	625	mW
Derate Above 25°C		5.0	mW/ºC
Power Dissipation at T _c =25°C	P_{D}	1.5	W
Derate Above 25°C		12	mW/ºC
Operating And Storage Junction Temperature Range	T_{j},T_{stg}	- 55 to +150	°C

THERMAL CHARACTERISTICS

Junction to Case	R _{th (j-c)}	83.3	°C/W
Junction to Ambient in free air	R _{th (j-a)}	200	°C/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	$I_{C}=1$ mA, $I_{B}=0$	300		V
Collector Base Voltage	V_{CBO}	$I_{C}=100\mu A, I_{E}=0$	300		V
Emitter Base Voltage	V_{EBO}	$I_{E}=100\mu A, I_{C}=0$	5.0		V
Collector Cut Off Current	I _{CBO}	$V_{CB}=200V, I_{E}=0,$		250	nA
Emitter Cut Off Current	I _{EBO}	V_{EB} =3 V , I_{C} =0,		100	nA
DC Current Gain	*h _{FE}	V_{CE} =10V, I_{C} =1mA	25		
		$V_{CE}=10V$, $I_{C}=10mA$	40		
		$V_{CE}=10V$, $I_{C}=30mA$	25		
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_C=20$ mA, $I_B=2$ mA		0.5	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	I _C =20mA, I _B =2mA		0.9	V

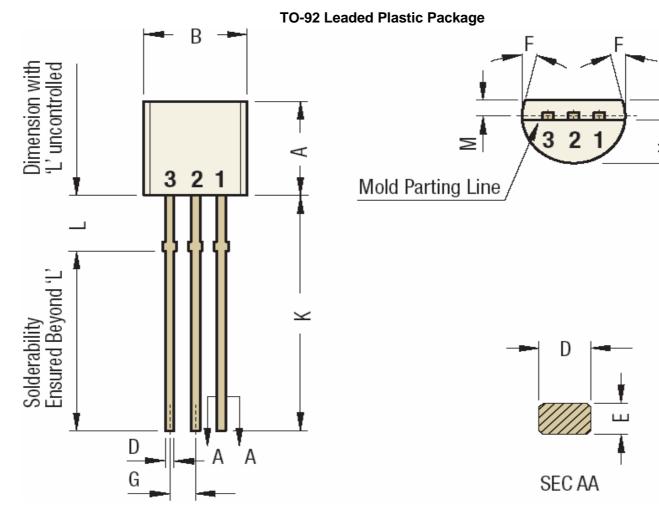
DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Current Gain Bandwidth Product	f _T	$I_C=10$ mA, $V_{CE}=20$ V, $f=100$ MHz	50		MHz
Collector Base Capacitance	C_cb	$V_{CB}=20V$, $I_{E}=0$, $f=1MHz$		6.0	pF

*PulseTest: Pulse Width <300ms, Duty Cycle<2%

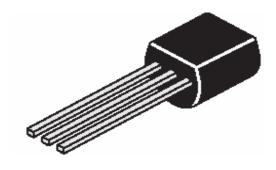
Plastic Package

For Lead Free Parts, Device Part # will be Prefixed with "T"



DIM	Min Max		
Α	4.32	5.33	
В	4.45	5.20	
С	3.18	4.19	
D	0.40	0.55	
E	0.30	0.55	
F	5°		

All Dimensions are in mm



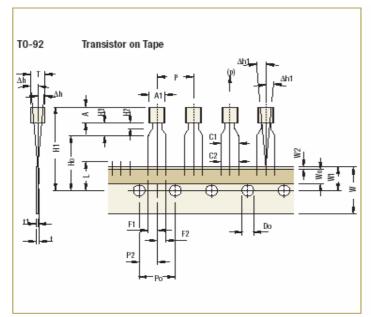
DIM Min Max G 1.14 1.40 Η 1.20 1.40 12.7 Κ 2.082 1.982 L 1.20 М 1.03

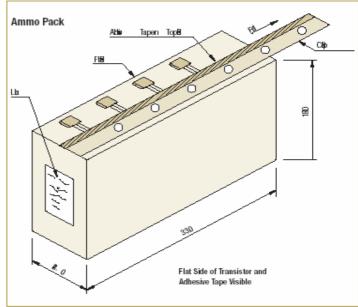
Collector Pin 1 Pin 2 Base Pin 3 **Emitter**

Plastic Package

For Lead Free Parts, Device Part # will be Prefixed with "T"

TO-92 Tape and Ammo Packaging





All Dimensions are in mm

Tape Specifications

Item description	Symbol
Body width	A1
Body height	A
Body thickness	T
Pitch of component ^{Cr}	P
Feed hole pitch ^{§1}	Po
Feed hole center to	
component centre§2	P2
Comp. alignment, Side view ^{§3}	Dh
Comp. alignment, Front view§3	Dh1
Tape width ^{Cr}	W
Hold down tape width ^{Cr}	Wo
Hole position	W1
Hold-down tape position	W2
Lead wire clinch height	Но
Component height	H1
Length of snipped leads	L
Feed hole diameter ^{Cr}	Do
Total tape thickness§4	t
Lead-to-lead distance ^{Cr}	F1, F2
Stand off	H2
Clinch height	Н3
Lead parallelismCr	C1-C2
Pull-out force	(p)

T0-92			
Min	Nom	Max	Tol
4.45		5.20	
4.32		5.33	
3.18		4.19	
	12.7		±1.0
	12.7		±0.3
	6.35		±0.4
	0	1.0	
	0	1.3	
	18		±0.5
	6		±0.2
	9		+0.7 -0.5
0.0		0.7	
	16		±0.5
		24.0	
		11.0	
	4		±0.2
		1.2	
2.4		2.7	
0.45		1.45	
		3.0	
		0.22	
6N			

Taping Specification

- · Maximum alignment deviation between leads not to be greater than 0.20 mm.
- Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
- · Hold down tape not to exceed beyond the edge(s) carrier tape and there shall be no exposure of adhesive.
- No more than 3 consecutive missing components is permitted.
- A tape trailer, having at least three feed holes is required after the last component.
- Splices shall not interfere with the sprocket feed holes.
- §1 Cumulative pitch error 1.0 mm/20 pitch.
- §2 To be measured at bottom of clinch.
- §3 At top of body.
- §4 t1 = 0.3 0.6 mm
- Cr Critical Dimension.

All Dimensions are in mm

For Lead Free Parts, Device Part # will be Prefixed with "T"

Packaging Information

T & A: Tape and Ammo Pack; T & R: Tape and Red; Bulk: Loose in Poly bags; Tube: Tube and Ammo Pack; k: 1.000

Package/Case		Std. Packing	Inner Carton			Outer Carton		
	I Packading IVne	Qty	Qty	Size L x W x H	Gross Weight	Qty	Size L x W x H	Gross Weight
Type		Qty	Qty	(cm)	(Kg)	Qty	(cm)	(Kg)
TO-92	Bulk	1,000	5K	19x19x8	1.10	80K	43x40x35	20.0
10-92	T&A	2,000	2K	32x4.5x20	0.70	40K	43x40x35	15.20

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Customer Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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